Effect of Feed Substrate Thickness on the Bandwidth and Radiation Characteristics of an Aperture-Coupled Microstrip Antenna with a High Permittivity Feed Substrate

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Abstract

The impedance bandwidth and radiation characteristics of an aperture-coupled microstrip line-fed patch antenna (ACMPA) with a high permittivity ($\epsilon_r=10$) feed substrate suitable for integration with a monolithic microwave integrated circuit (MMIC) are investigated for various feed substrate thicknesses through an experiment and computer simulation. The impedance bandwidth of an ACMPA with a high permittivity feed substrate increases as the feed substrate thickness decreases. Furthermore, the front-to-back ratio of an ACMPA with a high permittivity feed substrate increases and the cross-polarization level decreases as the feed substrate thickness decreases. As the impedance bandwidth of an ACMPA with a high permittivity feed substrate increases and its radiation characteristics improve as the feed substrate thickness decreases, the ACMPA configuration becomes suitable for integration with an MMIC.

Key Words: Aperture-Coupled Antenna, High Permittivity Feed Substrate, Monolithic Microwave Integrated Circuits (MMICs), Microstrip Antennas, Mutual Resonance.

I. INTRODUCTION

The antenna used for a next-generation base station antenna and radar is expected to be an active array antenna structure in which active amplifiers are mounted on each antenna element. Therefore, if an antenna is integrated into the front-end of a radio frequency module, the active array antenna structure will be simplified and its manufacturing cost will be reduced [1]. Microstrip patch antennas are used for many applications because of their many advantageous features, such as low profile, light weight, conformability, low fabrication cost, and suitability for integration with monolithic microwave integrated circuits (MMICs) [2].

MMICs are manufactured using high permittivity ($\epsilon_r > 10$)

materials, such as Si or GaAs. Therefore, antennas suitable for integration with MMICs should be designed on a high permittivity feed substrate. Many works have been conducted to develop antennas on a high permittivity feed substrate suitable for integration with an MMIC using various feeding methods [3–8].

An aperture-coupled microstrip line-fed patch antenna (ACMPA) can use two different dielectric substrates separated by a common ground plane. Therefore, an ACMPA with a low permittivity antenna substrate can be designed on a high permittivity feed substrate. This configuration of an ACMPA is particularly useful compared with other feeding methods when integrating an antenna with an MMIC. The impedance bandwidth of an ACMPA with a high permittivity feed substrate is

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usually smaller than that of an ACMPA with a low permittivity feed substrate [3]. When a patch antenna is integrated with an MMIC, the feed substrate thickness of the patch antenna must be thin to reduce the manufacturing cost and facilitate integration [3].

The effects of altering the parameters of the feed substrate on the impedance bandwidth and radiation characteristics of a microstrip line-fed aperture stacked patch antenna (ASPA) with a high permittivity feed substrate have been theoretically investigated to determine the suitability of the ASPA for integration with an MMIC [3]. The structure of an ASPA is composed of two patches mutually coupled to an aperture to obtain a large impedance bandwidth. In this study, the impedance bandwidth of the ASPA decreases as the thickness of the feed substrate decreases when the ASPA has a feed substrate permittivity of 10.2, which is suitable for integration with an MMIC. The ASPA structure has been shown to be unsuitable for integration with MMICs [3].

In the current study, we investigate the effect of the feed substrate thickness of an ACMPA with a high permittivity ($\epsilon_r=10$) feed substrate suitable for integration with an MMIC on the impedance bandwidth and radiation characteristics of the ACMPA through an experiment and computer simulation. High-Frequency Structure Simulator (HFSS) is used for the simulations in this work. We show that the impedance bandwidth of an ACMPA with a high permittivity feed substrate increases and that its radiation characteristics improve as the thickness of the feed substrate decreases.

This paper is organized as follows. In Section II, an ACMPA with a high permittivity feed substrate is designed for using a mutual resonance produced by the interaction of an aperture with a patch to obtain a large impedance bandwidth. The effect of the feed substrate thickness of the ACMPA on the impedance bandwidth and input impedance characteristics is investigated through a computer simulation. In Section III, the simulated and measured results of the impedance bandwidth and radiation characteristics of the ACMPCAs with various feed substrate thicknesses are presented. Section IV concludes the paper.

II. INPUT IMPEDANCE CHARACTERISTICS OF AN ACMPA VERSUS FEED SUBSTRATE THICKNESS

Fig. 1 shows the schematic diagram of an ACMPA. The antenna consists of two substrates separated by a common ground plane. The radiating microstrip patch element is etched on the top of the antenna substrate, and the microstrip feed line is etched on the bottom of the feed substrate. A rectangular aperture with dimensions of $L_{ap} \times W_{ap}$ is etched on the ground plane, and it is designed for using a mutual resonance produced

by the interaction between the aperture and the patch to obtain a large impedance bandwidth. The dimensions of the patch are $L_p \times W_p$. The relative permittivity and thickness of the feed (antenna) substrate are denoted as ϵ_{r1} (ϵ_{r2}) and h_1 (h_2), respectively. The feed substrate selected in this study is a Taconic CER-10 substrate with a relative permittivity of 10 (similar to that of high permittivity materials commonly used in MMIC fabrication) and a loss tangent of 0.0035. The antenna substrate selected in this study is a 3.2-mm-thick Taconic TLY-5 substrate ($\epsilon_r=2.2$, $\tan\delta=0.0009$). The microstrip line has a width of w_f and an open-circuited stub length of ℓ_s , and it is designed to have a characteristic impedance of 50Ω .

To investigate the effect of the feed substrate thickness on the impedance bandwidth of the ACMPA with $W_{ap}/L_{ap}=1/10$ [8], four ACMPCAs are designed with different feed substrate thicknesses. Table 1 shows the design parameters of the four ACMPCAs with the different feed substrate thicknesses required to obtain the maximum impedance bandwidth at a center frequency of 10 GHz.

Fig. 2(a) and (b) show the simulated return loss and real part of the normalized input impedance versus frequency, respectively, of the four ACMPCAs, with the design parameters shown in Table 1. In Fig. 2(a), the 10 dB return loss bandwidths of the ACMPCAs with $h_1=0.10$ mm, 0.28 mm, 0.78 mm, and 1.58 mm are 30.6% (8.49–11.56 GHz), 27.8% (8.66–11.46 GHz), 22.1% (8.88–11.09 GHz), and 18.1% (9.11–10.92 GHz), respectively. Fig. 2(a) shows that the 10 dB return loss bandwidth

Fig. 1. Geometry of an ACMPA.

Table 1. Design parameters of the four ACMPCAs with different feed substrate thicknesses

Model	h_1 (mm)	ϵ_{r1}	L_p (mm)	L_{ap} (mm)	W_{ap} (mm)	ℓ_s (mm)	w_f (mm)
A	0.10	10	7.2	7.0	0.70	0.88	0.11
B	0.28			6.5	0.65	0.80	0.32
C	0.78			5.8	0.58	0.79	0.79
D	1.58			5.3	0.53	0.47	1.39

Fig. 2. (a) Return loss and (b) real part of the normalized input impedance versus frequency of the four ACMs, with the design parameters shown in Table 1.

decreases as the feed substrate thickness increases. This phenomenon can be explained by the input impedance characteristics of the ACMs according to the feed substrate thickness.

Fig. 2(b) shows the real part of the normalized input impedance versus frequency of the four ACMs with different feed substrate thicknesses. In this study, the resonance frequency of the ACM is defined as the frequency in which the real part of the impedance reaches maximum [9]. When the feed substrate thickness is 0.10 mm, the resonance frequency of the aperture is about 14.22 GHz and that of the patch is about 9.60 GHz, so that the mutual resonance region between the two resonance frequencies is very large. When the feed substrate thickness is 0.28 mm (0.78 mm), the resonance frequency of the aperture is about 12.82 GHz (12.22 GHz) and that of the patch is about 9.62 GHz (9.78 GHz). When the feed substrate thickness is 1.58 mm, the resonance frequency of the aperture is about 11.88 GHz and that of the patch is about 10.08 GHz, so that the mutual resonance region between the two resonance frequencies is small compared with those of the other three feed substrate thicknesses. As the feed substrate thickness decreases, the mutual resonance region between the two resonance frequencies increases. The reasons for this outcome are as follows.

As the feed substrate thickness decreases, the coupling strength between the feedline and the aperture [10] as well as the aperture length for the maximum impedance bandwidth of the ACM increase. Therefore, the coupling strength between the aperture and the patch resonance increases as the feed substrate thickness decreases. As the frequency range between the aperture and the patch resonances increases because of the increase in the mutual resonance strength [11], the impedance bandwidth of an ACM caused by the mutual resonance increases as the feed substrate thickness decreases.

III. SIMULATION AND MEASUREMENT RESULT

Fig. 3 shows photographs of the three fabricated ACMs with different feed substrate thicknesses. The dielectric constants of the commercially available Taconic CER-10 substrates used as feed substrates are measured as 8.8, 9.3, and 9.75 for the

feed substrate thicknesses of 0.28 mm, 0.78 mm, and 1.58 mm, respectively. The antenna substrate used for the three fabricated ACMs shown in Fig. 3 is a 3.2-mm-thick Taconic TLY-5 substrate ($\epsilon_r = 2.2$, $\tan \delta = 0.0009$). Table 2 presents the design parameters of the fabricated ACMs required to obtain the maximum 10 dB return loss bandwidth at a center frequency of 10 GHz. As the feed substrate thickness decreases, the width of the 50 Ω microstrip transmission line decreases, as shown in Table 2. If the width of the microstrip transmission line on a high permittivity feed substrate decreases, the insertion loss between the connector and the transmission line increases. Therefore, to minimize the insertion loss, different connectors are used for the three fabricated ACMs with different feed substrate thicknesses, as shown in Fig. 3. To compare the simulation results with the measurement results, the relative permittivity of the feed substrate obtained from the measurement is used in the simulation.

Fig. 3. Photographs of the three fabricated ACMs with different feed substrate thicknesses: (a) $h_1 = 0.28$ mm, (b) $h_1 = 0.78$ mm, and (c) $h_1 = 1.58$ mm.

Table 2. Design parameters of the three ACMs with different feed substrate thicknesses

Model	h_1 (mm)	ϵ_{r1}	L_p (mm)	L_{ap} (mm)	W_{ap} (mm)	ℓ_s (mm)	w_f (mm)
A	0.28	8.8		6.3	0.63	0.80	0.31
B	0.78	9.3	7.2	5.7	0.57	0.80	0.81
C	1.58	9.75		5.4	0.54	0.45	1.41

Fig. 4. Simulated and measured return losses of the three ACMs with different feed substrate thicknesses: (a) $h_1 = 0.28$ mm, (b) $h_1 = 0.78$ mm, and (c) $h_1 = 1.58$ mm.

Fig. 4(a)–(c) show the simulated and measured return losses of the fabricated ACMPAs (Fig. 3) with feed substrate thicknesses of 0.28 mm, 0.78 mm, and 1.58 mm, respectively. The measured results are in good agreement with the simulated results. The measured 10 dB return loss bandwidths of the ACMPAs with $h_1=0.28$ mm, $h_1=0.78$ mm, and $h_1=1.58$ mm are 29.3% (8.67–11.65 GHz), 21.3% (8.94–11.08 GHz), and 17.4% (9.06–10.79 GHz), respectively. As the feed substrate thickness decreases, the impedance bandwidth increases.

Fig. 5 shows the input impedance loci plotted on a Smith chart of ACMPAs with a high permittivity ($\epsilon_r=10$) feed substrate for various feed substrate thicknesses. The inner circle on the Smith chart corresponds to the voltage standing wave ratio (VSWR) of 2. The input impedance loci have a loop inside the inner circle because of mutual resonance. The frequency range of the ACMPAs with $h_1=0.28$ mm, $h_1=0.78$ mm, and $h_1=1.58$ mm located inside the inner circle, on which the VSWR is 2, are 8.67–11.65 GHz, 8.94–11.08 GHz, and 9.06–10.79 GHz, respectively. Therefore, the 10 dB return loss bandwidths of the ACMPAs with $h_1=0.28$ mm, $h_1=0.78$ mm, and $h_1=1.58$ mm are 29.3%, 21.3%, and 17.4%, respectively.

Fig. 5. Input impedance loci plotted on a Smith chart of ACMPAs with a high permittivity ($\epsilon_r=10$) feed substrate for various feed substrate thicknesses.

Fig. 6. Simulated and measured E-plane radiation patterns of the three ACMPAs with different feed substrate thicknesses at 10 GHz. (a) $h_1=0.28$ mm, (b) $h_1=0.78$ mm, and (c) $h_1=1.58$ mm.

1.58 mm are 29.3%, 21.3%, and 17.4%, respectively.

Fig. 6 shows the simulated and measured E-plane radiation patterns of the three ACMPAs with different feed substrate thicknesses at 10 GHz. In the case of the co-polarization patterns, the measured results are in good agreement with the simulated results. The simulated cross-polarization gains of ACMPAs with $h_1=0.28$ mm, $h_1=0.78$ mm, and $h_1=1.58$ mm are -38.42 dBi, -38.84 dBi, and -29.80 dBi, respectively. When the feed substrate thickness is 1.58 mm, the cross-polarization gain increases by about 10 dB compared with those of the other two cases. The measured results for the cross-polarization gains of the three ACMPAs with different feed substrate thicknesses show larger values than the simulated results because of the alignment error of the antenna with respect to the probe in the measurement process.

Fig. 7 shows the simulated and measured H-plane radiation patterns of the three ACMPAs with different feed substrate thicknesses at 10 GHz. In the case of the co-polarization patterns, the measured results are in good agreement with the simulated results. The simulated cross-polarization gains of ACMPAs with $h_1=0.28$ mm, $h_1=0.78$ mm, and $h_1=1.58$ mm are -20.07 dBi, -7.15 dBi, and -6.64 dBi, respectively. The measured cross-polarization gains slightly differ from those of the simulated results. The measured cross-polarization gain of the ACMPA with $h_1=0.28$ mm is -15.20 dBi, which is 5 dB less than those of the other two cases.

Table 3 shows the measured radiation characteristics of the three ACMPAs with different feed substrate thicknesses at three different frequencies. The minimum broadside gain of 4.96 dBi is obtained at 11 GHz when the feed substrate thickness is 1.58 mm. The maximum broadside gain of 6.59 dBi is obtained at 11 GHz when the feed substrate thickness is 0.78 mm. As the return loss varies depending on the substrate thickness and frequency, as shown in Fig. 4, the broadside gain also varies depending on the substrate thickness and frequency. The difference in the broadside gain according to the substrate

Fig. 7. Simulated and measured H-plane radiation patterns of the three ACMPA with different feed substrate thicknesses at 10 GHz. (a) $h_1=0.28$ mm, (b) $h_1=0.78$ mm, and (c) $h_1=1.58$ mm.

thickness is not significant.

The front-to-back ratio (FBR) of the E-plane increases at 9 GHz and 10 GHz as the feed substrate thickness decreases. At 11 GHz, the FBR of the ACMPA with the largest feed substrate thickness ($h_1=1.58$ mm) has the highest FBR of 9.69 dB. However, the FBRs of the other two ACMPA are only 1.37 dB less than that of the ACMPA with the largest feed substrate thickness. The ACMPA with the smallest feed substrate thickness ($h_1=0.28$ mm) has the highest FBR of the H-plane of 18.08 dB and 13.84 dB at 10 GHz and 11 GHz, respectively. At 9 GHz, the ACMPA with a feed substrate thickness of 0.78 mm has the highest FBR of 12.06 dB, which is only 1.38 dB larger than that of the ACMPA with the smallest feed substrate thickness. The FBR in this work is defined as the ratio of the broadside gain to the maximum value of all backlobes within a

cone of $\pm 30^\circ$ around the negative z-axis with respect to the forward radiation [12].

As the feed substrate thickness decreases, the cross-polarization level of the H-plane decreases for all frequencies. The cross-polarization level of the E-plane also decreases at 9 GHz and 10 GHz as the feed substrate thickness decreases. At 11 GHz, the cross-polarization level of the E-plane of the ACMPA with the smallest feed substrate thickness ($h_1=0.28$ mm) is -20.89 dB, which is 4.22 dB larger than that of the ACMPA with $h_1=1.58$ mm. However, the simulated cross-polarization level of the E-plane of the ACMPA with $h_1=0.28$ mm is -40.97 dB at 11 GHz, which is 1.39 dB less than that of the ACMPA with $h_1=1.58$ mm. The measurement error is considered to have caused that the measured cross-polarization level of the E-plane of the ACMPA with $h_1=0.28$ mm to be larger

Table 3. Measured radiation characteristics of the three ACMPA with different feed substrate thicknesses at 9 GHz, 10 GHz, and 11 GHz

Model	h_1 (mm)	Observation plane	Broadside gain (dBi)			Front-to-back ratio (dB)			Cross-pol. level (dB)		
			9 GHz	10 GHz	11 GHz	9 GHz	10 GHz	11 GHz	9 GHz	10 GHz	11 GHz
A	0.28	E-plane	5.72	5.07	5.94	8.56	11.05	8.37	-24.09	-19.56	-20.89
		H-plane				10.64	18.08	13.84	-23.69	-20.27	-19.89
B	0.78	E-plane	5.09	5.72	6.59	4.22	9.74	8.32	-20.24	-17.67	-19.21
		H-plane				12.06	13.10	9.83	-17.41	-16.00	-16.97
C	1.58	E-plane	5.38	5.49	4.96	4.18	5.81	9.69	-17.66	-17.79	-25.11
		H-plane				4.60	14.85	6.78	-13.80	-15.70	-12.26

Table 4. Small FBRs and large cross-polarization levels of the three ACMPA with different feed substrate thicknesses at 9 GHz, 10 GHz, and 11 GHz

Model	h_1 (mm)	Front-to-back ratio (dB)			Cross-pol. level (dB)		
		9 GHz	10 GHz	11 GHz	9 GHz	10 GHz	11 GHz
A	0.28	8.56	11.05	8.37	-23.69	-19.56	-19.89
B	0.78	4.22	9.74	8.32	-17.41	-16.00	-16.97
C	1.58	4.18	5.81	6.78	-13.80	-15.70	-12.26

than that of the ACMPA with $h_1 = 1.58$ mm. The cross-polarization level in this work is defined as the maximum cross-polarization in the broadside relative to the maximum co-polarized field [13]. Moreover, the broadside gain is hardly affected by the feed substrate thickness.

The antenna performance is determined by a small FBR and a large cross-polarization level regardless of the E-plane and the H-plane. Table 4 shows the measured small FBRs and the large cross-polarization levels of the three ACMPA at three different frequencies. As indicated in the table, as the feed substrate thickness decreases, the FBR increases and the cross-polarization level decreases. However, this tendency may not be exactly shown because of the measurement error when the measured FBRs and cross-polarization levels of the three ACMPA at three different frequencies are compared in each plane.

IV. CONCLUSION

The radiation characteristics and impedance bandwidth of an ACMPA with a high permittivity ($\epsilon_r = 10$) feed substrate suitable for integration with an MMIC are investigated through an experiment and computer simulation for various feed substrate thicknesses. The impedance bandwidth of an ACMPA with a high permittivity feed substrate increases as the feed substrate thickness decreases. Furthermore, as the feed substrate thickness decreases, the FBR increases and the cross-polarization level decreases. The broadside gain is hardly affected by the feed substrate thickness.

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